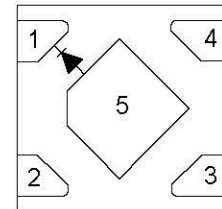


Features

- High capacitance ratio: $C_{0V} / C_{5V} = 3.4$ (typ.)
- Designed for high-volume, low-cost battery applications
- Available lead (Pb)-free and RoHS-compliant MSL-1 @ 260°C per JEDEC J-STD-020
- Available in tape and reel packaging
- Industry Standard DFN1x1-4L Package



Functional Block Diagram

Product Description

The YVC032P034R device is GaAs hyperabrupt junction varactor diodes specifically designed for VCOs applications, The specified high capacitance ratio and low R_s of YVC032P034R make it attractive for low phase noise VCOs in wireless systems up to and beyond 3.5GHz. Applications include low-noise and wideband UHF and VHF VCO for GSM, PCS, CDMA and analog phones.

Absolute Maximum Ratings

Characteristic	Rating	Unit
Forward current (I_F)	20	mA
Power dissipation (P_D)	250	mW
Storage temperature (T_{ST})	-55 to +150	°C
Operating temperature (T_{OP})	-55 to +125	°C
ESD human body model	Class1A	



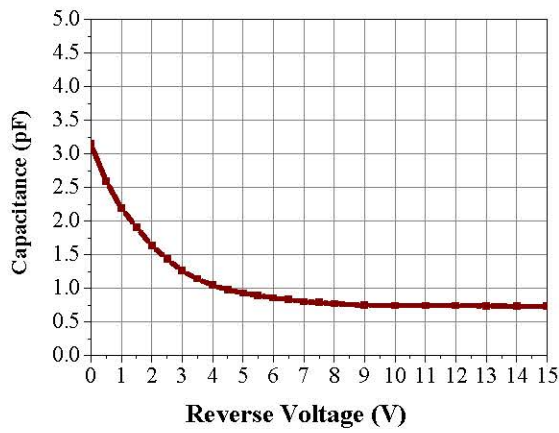
Caution!

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

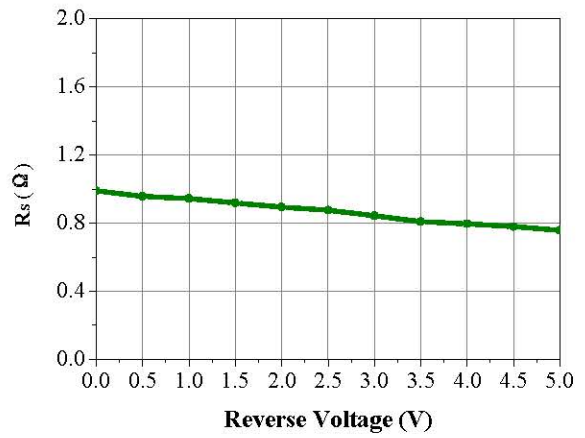
Electrical Specifications@25°C

Parameter	Condition	Specification			Unit
		Min.	Typ.	Max.	
Reverse Current (I_R)	$V_R = 15$ V			20	nA
Capacitance (C_T)	$C_T @ 0.5$ V, $V_R = 0.5$ V, $F = 1$ MHz		2.59		pF
Capacitance (C_T)	$C_T @ 5$ V, $V_R = 5$ V, $F = 1$ MHz		0.93		pF
Capacitance Ratio (C_{TR})	$C_T (0.5$ V)/ $C_T (5$ V)		2.78		
Series Resistance (R_S)	$V_R = 1$ V, $F = 100$ MHz			0.94	Ω
Breakdown Voltage (V_{BR})	$I_R = 10$ μA	20			V

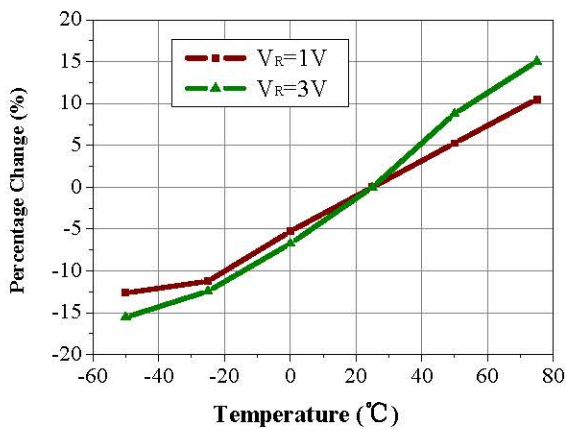
Typical Performance Data



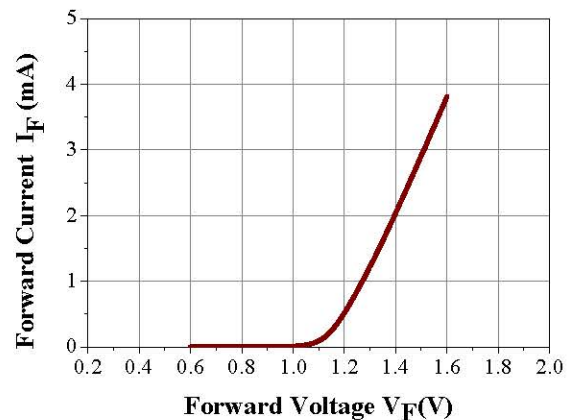
Capacitance vs. Reverse Voltage



Series Resistance vs. Reverse Voltage @ 100 MHz



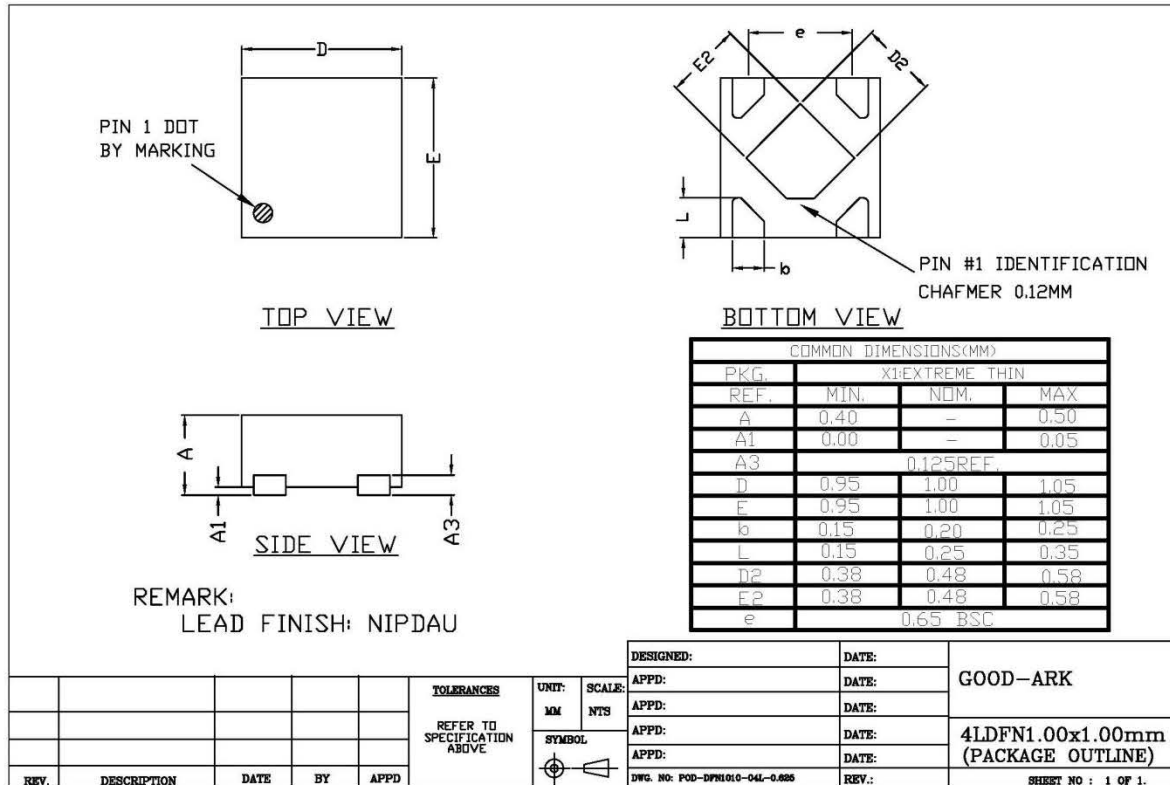
Relative Capacitance Change vs. Temperature



Forward I-V characteristic curve

Package Diagram

(Units: millimeters)



Part Number Naming Conventions:

(e.g.) **Y VC 032 P 034 R (D)**

① ② ③ ④ ⑤ ⑥ ⑦

- ① Company: INNOTION
- ② Product ID: (VC=Variable Capacitance Diode)
- ③ Capacitance (C_T)@ $V_R=0V$ is expressed by three-digit alphanumeric (e.g. 032=3.2pF, 228=22.8pF)
- ④ Capacitance Unit: pF
- ⑤ Capacitance ratio: C_{0V} / C_{5V} is expressed by three-digit alphanumeric (e.g. 034 is $C_{0V} / C_{5V} = 3.4$)
- ⑥ Ratio
- ⑦ There are two varactors inside, which can be used in parallel. For a single Varactor product, this letter is omitted.